





FZT591A

40V PNP SILICON PLANAR MEDIUM POWER TRANSISTOR IN SOT223

Features

- BV_{CEO} > -40V
- I_C = -1A high Continuous Current
- Low saturation voltage V_{CE(sat)} < -500mV @ -1A
- Complementary PNP Type: FZT591A
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

Mechanical Data

- Case: SOT223
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.112 grams (approximate)

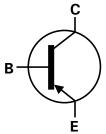
Applications

- Power MOSFET & IGBT gate driving
- Low loss power switching

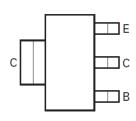




Top View



Device Symbol



Top View Pin-Out

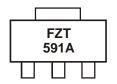
Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT591ATA	AEC-Q101	FZT591A	7	12	1,000
FZT591AQTA	Automotive	FZT591A	7	12	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
- 5. For packaging details, go to our website at http://www.diodes.com

Marking Information



FZT591A = Product Type Marking Code





FZT591A

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	Ic	-1	А
Base Current	I _B	-200	mA
Peak Pulse Current	I _{CM}	-2	A

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 6)	0	2	W
Power dissipation	(Note 7)	P _D	3	W
Thermal Decistores, lunction to Ambient	(Note 6)	7	62.5	°C/W
Thermal Resistance, Junction to Ambient	(Note 7)	R _{θJA}	41.7	°C/W
Thermal Resistance, Junction to Leads (Note 8	R _{0JL}	19.41	°C/W	
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-55 to +150	°C	

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

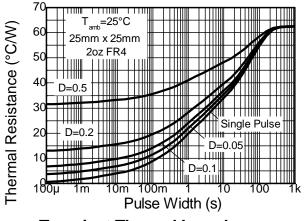
Notes:

- 6. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; device measured when operating in steady state condition.
- 7. Same as note (6), except the device is mounted on 50mm X 50mm single sided 2oz weight copper.
- 8. Thermal resistance from junction to solder-point (at the end of the collector lead).
- 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

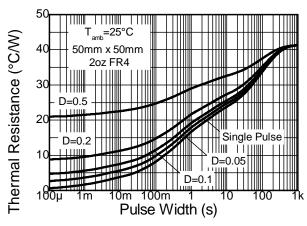




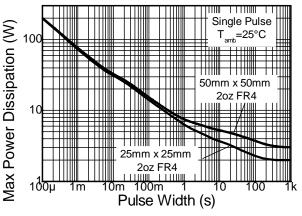
Thermal Characteristics and Derating Information



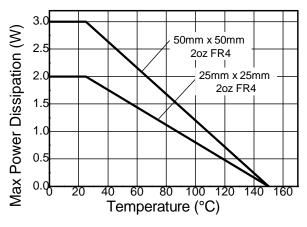
Transient Thermal Impedance



Transient Thermal Impedance



Pulse Power Dissipation



Derating Curve





FZT591A

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

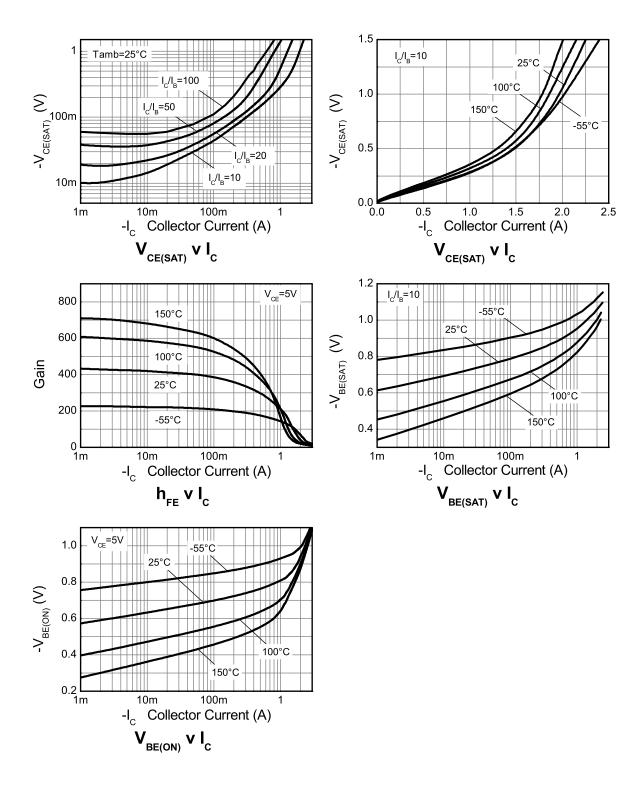
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-40	-	-	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	-40	_	_	V	$I_C = -10 \text{mA}$
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-	-	V	$I_E = -100 \mu A$
Collector Cut-off Current	I _{CBO}	_	_	-100	nA	V _{CB} = -30V
Collector Cut-off Current	I _{CES}	_	_	-100	nA	V _{CES} = -30V
Emitter Cut-off Current	I _{EBO}	_	_	-100	nA	$V_{EB} = -4V$
Collector-Emitter Saturation Voltage (Note 10)	$V_{CE(sat)}$	<u>-</u>	-	-0.2 -0.35 -0.5	V	$I_C = -100$ mA, $I_B = -1$ mA $I_C = -500$ mA, $I_B = -20$ mA $I_C = -1$ A, $I_B = -100$ mA
Base-Emitter Saturation Voltage (Note 10)	V _{BE(sat)}	_	_	-1.1	V	$I_C = -1A$, $I_B = -50mA$
Base-Emitter Turn-On Voltage (Note 10)	V _{BE(on)}	_	-	-1.0	V	$I_C = -1A, V_{CE} = -5V$
DC current transfer Static ratio (Note 10)	h _{FE}	300 300 250 160 30	- - - -	- 800 - - -		$\begin{split} I_{C} &= -1 \text{mA}, \ V_{CE} = -5 \text{V} \\ I_{C} &= -100 \text{mA}, \ V_{CE} = -5 \text{V} \\ I_{C} &= -500 \text{mA}, \ V_{CE} = -5 \text{V} \\ I_{C} &= -1 \text{A}, \ V_{CE} = -5 \text{V} \\ I_{C} &= -2 \text{A}, \ V_{CE} = -5 \text{V} \end{split}$
Transitional Frequency (Note 10)	f _T	150	-	_	MHz	$V_{CE} = -10V, I_{C} = -50mA$ f = 100MHz
Output Capacitance (Note 10)	C_{obo}	-	=	10	pF	V _{CB} = -10V. f = 1MHz

Notes: 10. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%





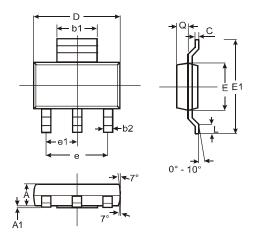
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)





Package Outline Dimensions

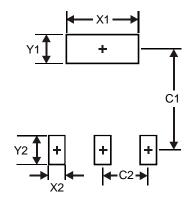
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A 1	0.010	0.15	0.05		
b1	2.90	3.10	3.00		
b2	0.60	0.80	0.70		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е			4.60		
e1	_		2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
X1	3.3
X2	1.2
Y1	1.6
Y2	1.6
C1	6.4
C2	2.3





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